

# D44H8 - D44H11 D45H8 - D45H11

## Complementary power transistors

### Features

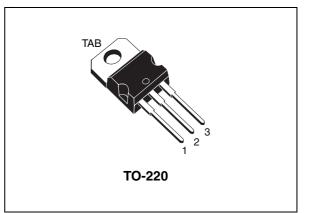
- Low collector-emitter saturation voltage
- Fast switching speed

### Applications

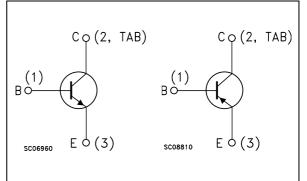
- Power amplifier
- Switching circuits

### Description

The devices are manufactured in low voltage multi epitaxial planar technology. They are intended for general purpose linear and switching applications.



### Figure 1. Internal schematic diagram



Order codes	Marking	Polarity	Package	Packaging
D44H8	D44H8	NPN	TO-220	Tube
D44H11	D44H11	NPN	TO-220	Tube
D45H8	D45H8	PNP	TO-220	Tube
D45H11	D45H11	PNP	TO-220	Tube

## 1 Absolute maximum ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V	Collector-emitter voltage (I <sub>B</sub> = 0) D44H8 - D45H8	60	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0) D44H11 - D45H11	80	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	5	V
۱ <sub>C</sub>	Collector current	10	A
I <sub>CM</sub>	Collector peak current	20	A
P <sub>TOT</sub>	Total dissipation at T <sub>case</sub> = 25 °C	50	W
T <sub>STG</sub>	Storage temperature	-55 to 150	°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative.

### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case max	2.5	°C/W
R <sub>thJA</sub>	Thermal resistance junction-ambient max	62.5	°C/W



## 2 Electrical characteristics

 $T_{case} = 25 \ ^{\circ}C$ ; unless otherwise specified.

	Table 4.	Electrical characteristics	
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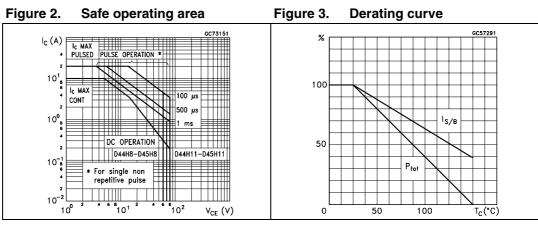
Symbol	Parameter	Test conditio	ns	Min.	Тур.	Max.	Unit
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA D44H8 - D45H8 D44H11 - D45H11		60 80	-		V
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	$V_{CE}$ = rated $V_{CEO}$			-	10	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			-	100	μA
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{\rm C} = 8 \text{ A}$ $I_{\rm B} =$	= 0.4 A		-	1	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation voltage	$I_{\rm C} = 8 \text{ A}$ $I_{\rm B} =$	= 0.8 A		-	1.5	V
h <sub>FE</sub> <sup>(1)</sup>	DC everyent sein	$I_{\rm C} = 2 \ {\rm A} \qquad V_{\rm CI}$	= 1 V	60	-		
	DC current gain	I <sub>C</sub> = 4 A V <sub>CI</sub>	= 1 V	40	-		

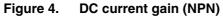
1. Pulse test: pulse duration  $\leq$  300 µs, duty cycle  $\leq$  2 %.

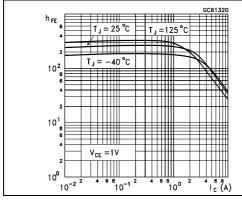
Note: For PNP types voltage and current values are negative.

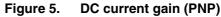


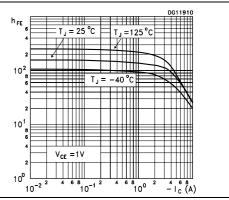
### 2.1 Electrical characteristics (curves)

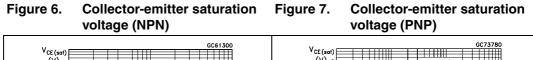


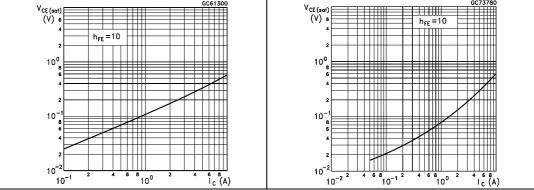
















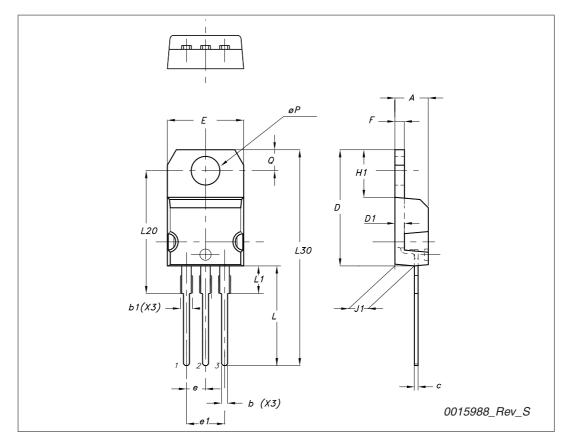
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



Dim	mm			
Dim	Min	Тур	Мах	
A	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.70	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13		14	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
ØP	3.75		3.85	
Q	2.65		2.95	







## 4 Revision history

Table 5.Document revision history

Date	Revision	Changes
21-Jun-2004	4	Document migration, no content change.
20-Oct-2009	5	Updated mechanical data.



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